

CLAIMS

What is claimed is:

1 1. A method for driving a diode, comprising:
 2 (a) providing a power supply input voltage upto about three volts;
 3 (b) selecting of an amount of current from at least two amounts of current to flow
 4 through a diode; said selecting of said amount of at least two amounts of current
 5 based upon a voltage of at least two input values;
 6 (c) directing said selected amount of current to flow through said diode; wherein at
 7 least two current sources operating to produce said at least two amounts of current
 8 are accommodated with headroom voltage provided by said input voltage to
 9 operate correctly without being connected to an alternating current coupling
 10 circuit.

1 2. The method as claimed in claim 1, wherein said method is capable of
 2 driving a vertical cavity surface emitting laser diode.

1 3. The method as claimed in claim 1, wherein a first current source of said at
 2 least two current sources produces an amount of current substantially equal to one of said
 3 at least two amounts of current selected.

1 4. The method as claimed in claim 1, wherein said selecting one of said at
 2 least two amounts of current is accomplished by a pair of transistors operating as a
 3 differential switch.

1 5. A circuit for providing a semiconductor laser drive current, comprising:

- 2 (a) a power supply input voltage upto about three volts;
- 3 (b) a differential switch for selecting an amount of current from at least two amounts
- 4 of current depending upon the voltage of each of at least two inputs; said
- 5 differential switch being formed from a pair of transistors; and
- 6 (c) at least two current sources, said at least two current sources being capable of
- 7 producing said at least two amounts of current by at least one of independent and
- 8 combined operation, wherein a suitable amount of headroom voltage for said at
- 9 least two current sources is obtained by the amount of voltage provided by said
- 10 input voltage less a voltage drop across a device being driven by said selected
- 11 current and a voltage drop across said pairs of transistors during operation of said
- 12 circuit.

1 6. The circuit as claimed in claim 5, wherein said pair of transistors are

2 bipolar transistors.

1 7. The circuit as claimed in claim 5, wherein approximately a volt of

2 headroom voltage is obtained by the amount of voltage provided by said input voltage

3 less a voltage drop across said device being driven by said selected current and a voltage

4 drop across said pairs of transistors during operation of said circuit.

1 8. A circuit, comprising:

2 (a) at least two inputs;

3 (b) a first transistor connected to a first input of said at least two inputs;

4 (c) a second transistor connected to a second input of said at least two inputs;

5 (d) a first current source capable of generating a first amount of current connected to
6 said first and second transistors; and

7 (a) a second current source capable of generating a second amount of current
8 connected to said second transistor, wherein a second amount of current and an
9 amount of current substantially equal to a second amount of current less a first
10 amount of current is capable of being delivered to a device.

1 9. The circuit as claimed in claim 8, wherein a second amount of current is
2 delivered to said device when said first input is a higher voltage than said second input.

1 10. The circuit as claimed in claim 8, wherein said amount of current
2 substantially equal to a second amount of current less a first amount of current is
3 delivered to said laser diode when said second input is a higher voltage than said first
4 input.

1 11. The circuit as claimed in claim 8, wherein said first and second transistors
2 are bipolar transistors.

1 12. The circuit as claimed in claim 8, wherein said first input is connected to a
2 base of said first transistor.

1 13. The circuit as claimed in claim 8, wherein said second input is connected
2 to a based of said second transistor.

1 14. The circuit as claimed in claim 8, wherein said first current source is
2 connected to an emitter of each of said first and second transistors.

1 15. The circuit as claimed in claim 8, wherein said second current source is
2 connected to a collector of said second transistor.

1 16. The circuit as claimed in claim 8, wherein said laser diode is a vertical
2 cavity surface emitting laser diode, said vertical cavity surface emitting laser diode being
3 connected to a collector of said second transistor.

1 17. The circuit as claimed in claim 8, wherein said circuit is capable of driving
2 said laser diode with a voltage supply of three volts or less without alternative current
3 coupling.

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1 18. A circuit for providing a semiconductor laser drive current, comprising:

- 2 (a) means for providing a power supply input voltage, said power supply input
3 voltage upto about three volts;
- 4 (b) means for selecting an amount of current from at least two amounts of current to
5 flow through a diode; said selecting means being capable of analyzing the voltage
6 of each of at least two inputs;
- 7 (c) means for generating said at least two amounts of current; and
- 8 (a) means for directing said selected amount of current to flow through said diode;
9 wherein said generating means is capable of operating correctly without said
10 circuit being connected with an alternating current coupling circuit.